NSN 5962-01-075-7606

Memory Microcircuit - Page 1 of 1



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Body Length:

0.440 inches

Body Width:

Between 0.240 inches and 0.325 inches

Body Height:

0.085 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and schottky and bipolar and 3-state output

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Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

5.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, low to high level output and 10.00 nanoseconds propagation delay time, high to low level output and 89.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

B2577-932820 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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